

NOT RECOMMENDED FOR NEW DESIGN USE DMP3007SPS



DMP3010LPS

P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

| BV _{DSS} | R _{DS(ON)} | I _D T _A = +25°C |
|-------------------|--|--|
| -30V | $7.5 \text{m}\Omega$ @ $V_{GS} = -10V$ | -36A |
| | $10m\Omega @ V_{GS} = -4.5V$ | -31A |

Description

This new generation 30V P-Channel Enhancement Mode MOSFET is designed to minimize R_{DS(ON)}, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

PowerDI5060-8

Applications

- Notebook Battery Power Management
- DC-DC Converters
- Loadswitch

Features

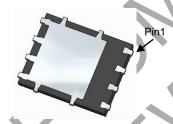
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- ESD HBM Protected up to 1kV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP3010LPSQ)

Mechanical Data

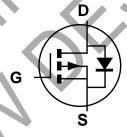
- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
 Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



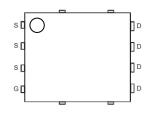
Top View



Bottom View



Internal Schematic



Top View Pin Configuration

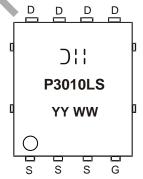
Ordering Information (Note 4)

| Part Number | Compliance | Case | Packaging |
|---------------|------------|---------------|-------------------|
| DMP3010LPS-13 | Standard | PowerDI5060-8 | 2,500/Tape & Reel |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



☐ = Manufacturer's Marking P3010LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 17 = 2017)WW = Week (01 to 53)

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DMP3010LPS

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|------------------|--|----------------|----------------|---|
| Drain-Source Voltage | V _{DSS} | -30 | V | | |
| Gate-Source Voltage | V _{GSS} | ±20 | V | | |
| Continuous Drain Current (Note 7) V _{GS} = -10V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | -36 -29 | Α |
| Continuous Drain Current (Note 7) V _{GS} = -4.5V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | ID | -31 -25 | А |
| Continuous Drain Current (Note 6) V _{GS} = -10V | Steady State | $T_A = +25$ °C $T_A = +70$ °C | I _D | -14.5 -11.5 | А |
| Pulsed Drain Current (Notes 6 & 9) | I _{DM} | -100 | Α | | |
| Avalanche Current (Notes 10 & 11) | I _{AS} | -17.5 | Α | | |
| Avalanche Energy (Notes 10 & 11) L = 1mH | E _{AS} | 153 | mJ | | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|----------------------|-------------|------|
| Power Dissipation (Note 5) | PD | 1.26 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5) | R ₀ JA | 97 | °C/W |
| Power Dissipation (Note 6) | P _D | 2.18 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6) | R _{θJA} | 55 | °C/W |
| Power Dissipation (Note 7) | P_{D} | 14.37 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7) | R ₀ JA | 8.7 | °C/W |
| Power Dissipation (Notes 7 & 8) | P _D | 58.7 | W |
| Thermal Resistance, Junction to Case @T _C = +25°C (Notes 7 & 8) | $R_{	heta JC}$ | 2.13 | °C/W |
| Operating and Storage Temperature Range | TJ, T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min 🆠 | Тур | Max | Unit | Test Condition | |
|---|----------------------|---------------------------------------|-------|------|-------|---|--|
| OFF CHARACTERISTICS (Note 11) | | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | _ | | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | 4 | -1.0 | μΑ | $V_{DS} = -30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | ļ | | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 11) | | | , | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -1.1 | -1.6 | -2.1 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ | |
| Static Drain-Source On-Resistance | D | V - | 5.7 | 7.5 | mΩ | $V_{GS} = -10V, I_{D} = -10A$ | |
| Static Diain-Source On-Resistance | R _{DS} (ON) | _ | 7.2 | 10 | 11122 | $V_{GS} = -4.5V, I_D = -10A$ | |
| Forward Transfer Admittance | Y _{fs} | _ | 30 | - | S | $V_{DS} = -15V, I_{D} = -10A$ | |
| Diode Forward Voltage | V _{SD} | _ | -0.65 | -1.0 | V | $V_{GS} = 0V, I_{S} = -1A$ | |
| DYNAMIC CHARACTERISTICS (Note 12) | | | | | | | |
| Input Capacitance | Ciss | _ | 6,234 | _ | pF | | |
| Output Capacitance | Coss | _ | 1,500 | _ | pF | $V_{DS} = -15V, V_{GS} = 0V,$ - f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | _ | 774 | | pF | -1 = 1.0MH2 | |
| Gate Resistance | Rg | _ | 1.28 | _ | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge (V _{GS} = -10V) | Q_g | _ | 126.2 | 1 | nC | $V_{DS} = -15V, I_{D} = -10A$ | |
| Total Gate Charge (V _{GS} = -4.5V) | Q_g | _ | 59.2 | _ | nC | 45)/)/ 45)/ | |
| Gate-Source Charge | Q_{gs} | _ | 16.1 | _ | nC | $V_{DS} = -15V, V_{GS} = -4.5V,$ | |
| Gate-Drain Charge | Q_{gd} | _ | 15.7 | _ | nC | $I_D = -10A$ | |
| Turn-On Delay Time | t _{D(ON)} | _ | 11.4 | _ | ns | | |
| Turn-On Rise Time | t _R | _ | 9.4 | | ns | $V_{DS} = -15V, V_{GEN} = -10V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 260.7 | _ | ns | $R_G = 6\Omega$, $I_D = -1A$ | |
| Turn-Off Fall Time | t _F | _ | 99.3 | _ | ns | | |

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. Device mounted on FR-4 PCB with infinite heatsink.

8. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. 9. Repetitive rating, pulse width limited by junction temperature, 10s pulse, duty cycle = 1%.

10. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25$ °C.

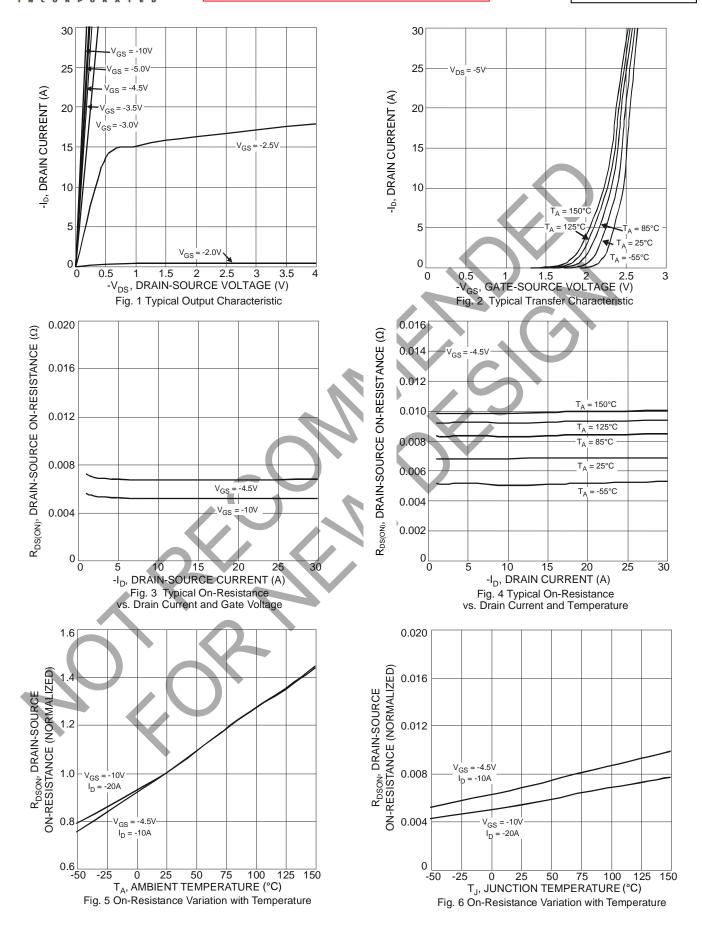
11. Short duration pulse test used to minimize self-heating effect.

12. Guaranteed by design. Not subject to product testing.



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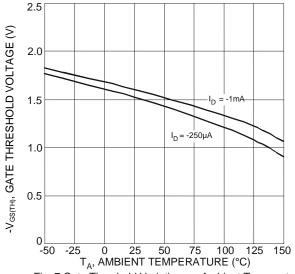
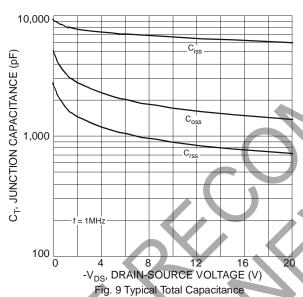
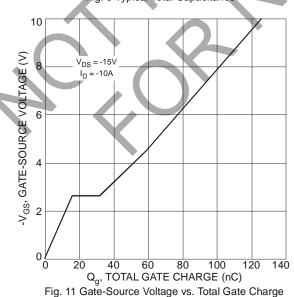


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





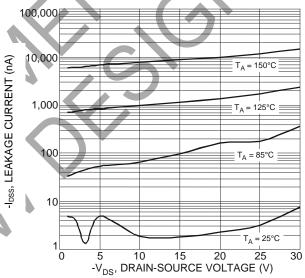
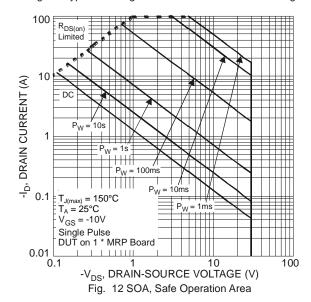


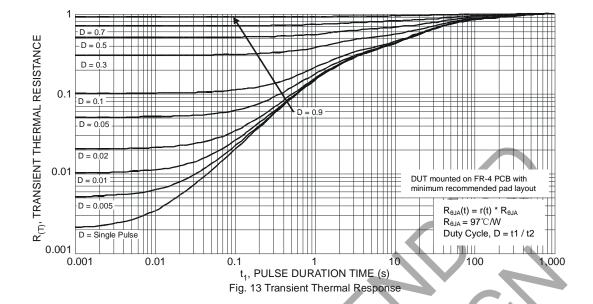
Fig. 10 Typical Leakage Current vs. Drain-Source Voltage







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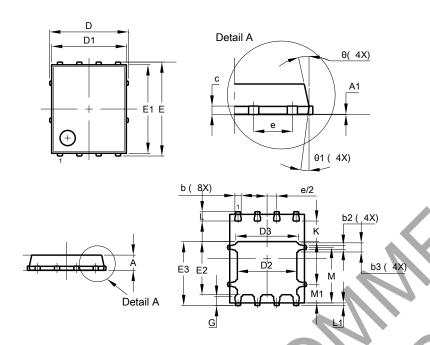




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

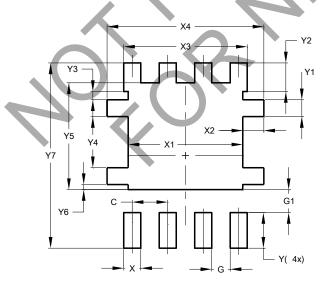


| PowerDI5060-8 | | | | | | |
|----------------------|----------|----------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.90 | 1.10 | 1.00 | | | |
| A1 | 0.00 | 0.05 | - | | | |
| b | 0.33 | 0.51 | 0.41 | | | |
| b2 | 0.200 | 0.350 | 0.273 | | | |
| b3 | 0.40 | 0.80 | 0.60 | | | |
| c | 0.230 | 0.330 | 0.277 | | | |
| D | 5.15 BSC | | | | | |
| D1 | 4.70 | 5.10 | 4.90 | | | |
| D2 | 3.70 | 4.10 | 3.90 | | | |
| D3 | 3.90 | 4.30 | 4.10 | | | |
| Е | (| 6.15 BSC | | | | |
| E1 | 5.60 | 6.00 | 5.80 | | | |
| E2 | 3.28 | 3.68 | 3.48 | | | |
| E3 | 3.99 | 4.39 | 4.19 | | | |
| e | 1.27 BSC | | | | | |
| G | 0.51 | 0.71 | 0.61 | | | |
| K | 0.51 | _ | - | | | |
| ١ | 0.51 | 0.71 | 0.61 | | | |
| 1 | 0.100 | 0.200 | 0.175 | | | |
| M | 3.235 | 4.035 | 3.635 | | | |
| M1 | 1.00 | 1.40 | 1.21 | | | |
| Θ | 10° | 12° | 11° | | | |
| Θ1 | 6° | 8° | 7° | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



| C 1.270 G 0.660 G1 0.820 X 0.610 X1 4.100 X2 0.755 | |
|--|--|
| G1 0.820 X 0.610 X1 4.100 | |
| X 0.610 X1 4.100 | |
| X1 4.100 | |
| | |
| X2 0.755 | |
| | |
| X3 4.420 | |
| X4 5.610 | |
| Y 1.270 | |
| Y1 0.600 | |
| Y2 1.020 | |
| Y3 0.295 | |
| Y4 1.825 | |
| Y5 3.810 | |
| Y6 0.180 | |
| Y7 6.610 | |



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